



RoHS Directive compatibility information http://www.mew.co.jp/ac/e/environment/

FEATURES

1. Compact with high sensitivity The high-efficiency polarized electromagnetic circuits of the 4-gap balanced armature and our exclusive spring alignment method achieves, with high-sensitivity in a small package, a relay that can be directly controlled by a driver chip.

4 A CAPACITY, THE VARIETY OF CONTACT ARRANGEMENTS

2. Strong resistance to vibration and shock

Use of 4G-BA technology realizes strong resistance to vibration and shock.

3. High reliability and long life Our application of 4G-BA technology, along with almost perfectly complete twin contact, ensures minimal contact bounce and high reliability.

4. Ability to provide wide-ranging control

Use of 4G-BA technology with gold-clad silver alloy contacts in a twin contact structure enables control across a broad range from microcurrents of 100 μ A 100 mV DC to 4 A 250 V AC.

5. Latching types available

With 4G-BA technology, as well as single side stable types, convenient 2 coil latching types for circuit memory applications are also available.

6. Wide variety of contact formations available

The compact size of the 4G-BA mechanism enables the provision of many kinds of package, including 2a2b, 3a1b, and 4a. These meet your needs across a broad range of applications.

S RELAYS

9) (D

7. Low thermal electromotive force relay

High sensitivity (low power consumption) is realized by 4G-BA technology. Separation of the coil and spring sections has resulted in a relay with extremely low

levels of thermal electromotive force (approx. $0.3 \ \mu\text{V}$).

8. DIL terminal array

Deployed to fit a 2.54 mm .100 inch grid, the terminals are presented in DIL arrays which match the printed circuit board terminal patterns commonly in international use.

9. Relays that push the boundaries of relay efficiency

High-density S relays take you close to the limits of relay efficiency.

TYPICAL APPLICATIONS

Telecommunications equipment, data processing equipment, facsimiles, alarm equipment, measuring equipment.

4-GAP BALANCED ARMATURE MECHANISM

1. Armature mechanism has excellent resistance to vibration and shock The armature structure enables free rotation around the armature center of gravity. Because the mass is maintained in balance at the fulcrum of the axis of rotation, large rotational forces do not occur even if acceleration is applied along any vector. The mechanism has proven to have excellent resistance to vibration and shock. All our S relays are based on this balanced armature mechanism, which is able to further provide many other characteristics.

2. High sensitivity and reliability provided by 4-gap balanced armature mechanism

As a (polarized) balanced armature, the S relay armature itself has two permanent magnets. Presenting four interfaces, the armature has a 4-gap structure. As a result, the rotational axis at either end of the armature is symmetrical and, in an energized into a polarized state, the twin magnetic armature interfaces are subject to repulsion on one side and attraction on the other. This mechanism, exclusive to Matsushita Electric Works, provides a highly efficient polarized magnetic circuit structure that is both highly sensitive and has a small form factor. Moreover, suitability for provision with many types of contact array and other advantages promise to make it possible to provide many of the various characteristics that are coming to be demanded of relays.

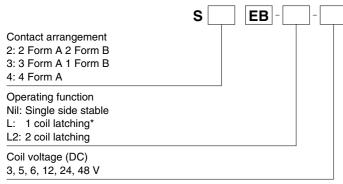
HOW IT WORKS (single side stable type)

1) When current is passed through the coil, the yoke becomes magnetic and polarized.

2) At either pole of the armature, repulsion on one side and attraction on the other side is caused by the interaction of the poles and the permanent magnets of the armature. 3) At this time, opening and closing operates owing to the action of the simultaneously moulded balanced armature mechanism, so that when the force of the contact breaker spring closes the contact on one side, on the other side, the balanced armature opens the contact (2a2b).

Repulsion Permanent magnet Residual plate Attraction Repulsion

ORDERING INFORMATION



Notes: 1. *1 coil latching type are manufactured by lot upon receipt of order. 2. UL/CSA approved type is standard.

TYPES

0	Naminal anil calta an	Single side stable	2 coil latching		
Contact arrangement	Nominal coil voltage	Part No.	Part No.		
2 Form A 2 Form B	3V DC	S2EB-3V	S2EB-L2-3V		
	5V DC	S2EB-5V	S2EB-L2-5V		
	6V DC	S2EB-6V	S2EB-L2-6V		
	12V DC	S2EB-12V	S2EB-L2-12V		
	24V DC	S2EB-24V	S2EB-L2-24V		
	48V DC	S2EB-48V	S2EB-L2-48V		
	3V DC	S3EB-3V	S3EB-L2-3V		
	5V DC	S3EB-5V	S3EB-L2-5V		
3 Form A 1 Form B	6V DC	S3EB-6V	S3EB-L2-6V		
	12V DC	S3EB-12V	S3EB-L2-12V		
	24V DC	S3EB-24V	S3EB-L2-24V		
	48V DC	S3EB-48V	S3EB-L2-48V		
	3V DC	S4EB-3V	S4EB-L2-3V		
	5V DC	S4EB-5V	S4EB-L2-5V		
4 Form A	6V DC	S4EB-6V	S4EB-L2-6V		
4 Form A	12V DC	S4EB-12V	S4EB-L2-12V		
	24V DC	S4EB-24V	S4EB-L2-24V		
	48V DC	S4EB-48V	S4EB-L2-48V		

Standard packing: Tube: 50 pcs.; Case: 500 pcs.

RATING

1. Coil data

1) Single side stable

Туре	Nominal coil voltage	Pick-up voltage (at 20°C 68°F)	Drop-out voltage (at 20°C 68°F)	Nominal operating current [±10%] (at 20°C 68°F)	Coil resistance [±10%] (at 20°C 68°F)	Nominal operating power	Coil inductance	Max. allowable voltage (at 40°C 104°F)
	3V DC	DC 70%V or less DC of nominal DC voltage	10%V or more of nominal voltage (Initial)	66.7mA	45Ω	200mW	Approx. 23mH	5.5V DC
Standard -	5V DC			38.5mA	130Ω	192mW	Approx. 65mH	9.0V DC
	6V DC			33.3mA	180Ω 200mW		Approx. 93mH	11.0V DC
	12V DC			16.7mA	720Ω	200mW	Approx. 370mH	22.0V DC
	24V DC			8.4mA	2,850Ω	202mW	Approx. 1,427mH	44.0V DC
	48V DC]		5.6mA	8,500Ω	271mW	Approx. 3,410mH	75.0V DC

2) 2 coil latching

Туре	Nominal coil voltage	Set voltage (at 20°C 68°F)	Reset voltage (at 20°C 68°F)	Nominal operating current [±10%] (at 20°C 68°F)		Coil resistance [±10%] (at 20°C 68°F)		Nominal operating power (at 20°C 68°F)		Coil inductance		Max. allowable voltage
				Set coil	Reset coil	Set coil	Reset coil	Set coil	Reset coil	Set coil	Reset coil	(at 40°C 104°F)
	3V DC		70%V or less of nominal voltage (Initial)	66.7mA	66.7mA	45Ω	45Ω	200mW	200mW	Approx. 10mH	Approx. 10mH	5.5V DC
Standard -	5V DC	70%V or less of nominal voltage (Initial)		38.5mA	38.5mA	130Ω	130Ω	192mW	192mW	Approx. 31mH	Approx. 31mH	9.0V DC
	6V DC			33.7mA	33.7mA	180Ω	180Ω	200mW	200mW	Approx. 40mH	Approx. 40mH	11.0V DC
	12V DC			16.7mA	16.7mA	720Ω	720Ω	200mW	200mW	Approx. 170mH	Approx. 170mH	22.0V DC
	24V DC			8.4mA	8.4mA	2,850Ω	2,850Ω	202mW	202mW	Approx. 680mH	Approx. 680mH	44.0V DC
	48V DC			7.4mA	7.4mA	6,500Ω	6,500Ω	355mW	355mW	Approx. 1,250mH	Approx. 1,250mH	65.0V DC

2. Specifications

Characteristics		Item	Specifications				
	Arrangement		2 Form A 2 Form B, 3 Form A 1 Form B, 4 Form A				
Contact	Initial contact resista	nce, max.	Max. 50 mΩ (By voltage drop 6 V DC 1A)				
	Electrostatic capacita	ance (initial)	Approx. 3pF				
	Contact material		Au clad Ag alloy (Cd free)				
	Thermal electromotiv (initial)	re force (at nominal coil voltage)	Approx. 3µV				
	Nominal switching ca	pacity (resistive load)	4 A 250 V AC, 3 A 30 V DC				
	Max. switching powe	r (resistive load)	1,000 VA, 90 W				
	Max. switching voltage	je	250 V AC, 48 V DC (30 to 48 V DC at less than 0.5 A)				
Rating	Max. switching currer	nt	4 A (AC), 3 A (DC)				
	Minimum operating p	ower	100 mW (Single side stable, 2 coil latching)				
	Nominal operating po	ower	200 mW (Single side stable, 2 coil latching)				
	Min. switching capac	ity (Reference value)*1	100µA 100 m V DC				
	Insulation resistance	(Initial)	Min. 10,000M Ω (at 500V DC) Measurement at same location as "Initial breakdown voltage" section.				
	Breakdown voltage (Initial)	Between open contacts	750 Vrms for 1min. (Detection current: 10mA.)				
		Between contact sets	1,000 Vrms for 1min. (Detection current: 10mA.)				
Electrical		Between contact and coil	1,500 Vrms for 1min. (Detection current: 10mA.)				
characteristics	Temperature rise (at	20°C 68°F)	Max. 35°C (By resistive method, nominal voltage applied to the coil; contact carrying current: 4A.)				
	Operate time [Set tim	ne] (at 20°C 68°F)	Max. 15 ms [15 ms] (Nominal voltage applied to the coil, excluding contact bounce time.)				
	Release time [Reset	time] (at 20°C 68°F)	Max. 10 ms [15 ms] (Nominal voltage applied to the coil, excluding contact bounce time.) (without diode)				
	Shock resistance	Functional	Min. 490 m/s ² (Half-wave pulse of sine wave: 11 ms; detection time: 10µs.)				
Mechanical characteristics		Destructive	Min. 980 m/s ² (Half-wave pulse of sine wave: 6 ms.)				
		Functional	10 to 55 Hz at double amplitude of 3 mm (Detection time: 10µs.)				
	Vibration resistance	Destructive	10 to 55 Hz at double amplitude of 4 mm				
Free estad life	Mechanical		Min. 10 ⁸ (at 50 cps)				
Expected life	Electrical		Min. 10 ⁵ (4 A 250 V AC), Min. 2×10 ⁵ (3 A 30 V DC) (at 20 cpm)				
Conditions	Conditions for operat	ion, transport and storage $*_2$	Ambient temperature: -55° C to $+65^{\circ}$ C -67° F to $+149^{\circ}$ F Humidity: 5 to 85% R.H. (Not freezing and condensing at low temperature)				
	Max. operating speed	t	20 cpm for maximum load, 50 cps for low-level load (1 mA 1 V DC)				
Unit weight			Approx. 8 g .28 oz				

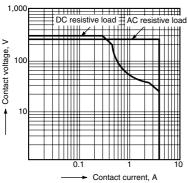
Notes: *1 This value can change due to the switching frequency, environmental conditions, and desired reliability level, therefore it is recommended to check this with the actual load. *2 Refer to 6. Conditions for operation, transport and storage mentioned in AMBIENT ENVIRONMENT.

REFERENCE DATA

1. Maximum switching power

4.-(1) Coil temperature rise

Tested Sample: S4EB-24V, 4 Form A



100 ↓ Life. 5 30 125 V AC (cosφ = 1.0) 250 V AC (cosφ = 1.0) 10 ō 2 Contact current, A

100

90

70

60

50

40

30

20

10

0

ů 80

Temperature rise

2. Life curve

1,000

500

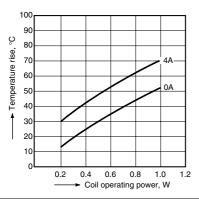
×10⁴

4.-(2) Coil temperature rise Tested Sample: S4EB-24V, 4 Form A

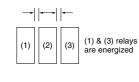
Coil operating power, 0.2 W

Contact current, A

5

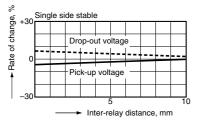


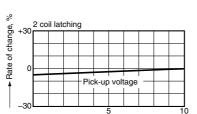
6. Influence of adjacent mounting



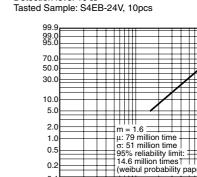
Note: When installing an S-relay near another, and there is no effect from an external magnetic field, be sure to leave at least 10 mm .394 inch between relays in order to achieve the performance listed in the catalog.

1 2 3 4 5 6





Inter-relay distance, mm



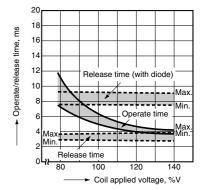
3. Contact reliability

Condition: 1V DC, 1mA Detection level 10 Ω

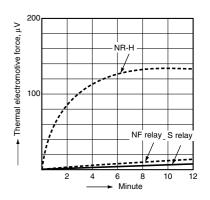
> 0.2 0.1

1.0 No. of operations, ×107

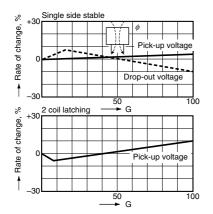
5. Operate and release time (Single side stable type) Tested Sample: S4EB-24V, 10pcs

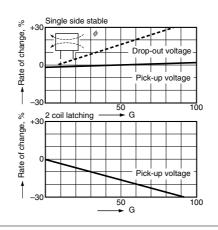


7. Thermal electromotive force



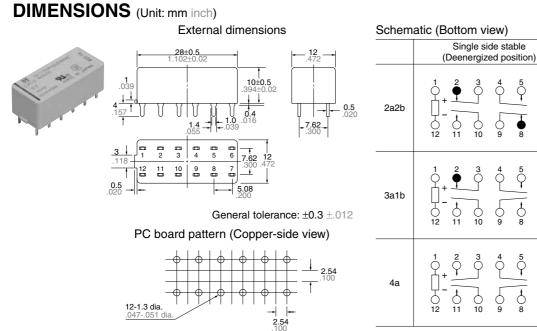
8. Effect from an external magnetic field





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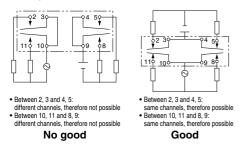
10.0



Tolerance: ±0.1 ±.003

NOTES

1. Based on regulations regarding insulation distance, there is a restriction on same-channel load connections between terminals No. 2, 3 and 4, 5, as well as between No. 8, 9 and 10, 11. See the figure below for an example.



(1 Form A 1 Form B types) operates and releases, contacts a and b may go ON at the same time.

2. Please note that when this relay

2 coil latching

(Reset condition)

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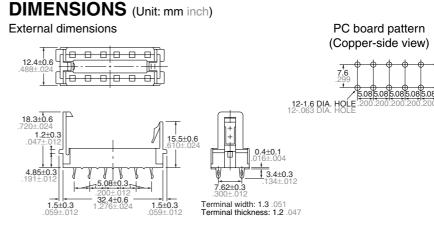
For Cautions for Use, see Relay Technical Information.





ACCESSORIES





S-PS

RoHS Directive compatibility information http://www.mew.co.jp/ac/e/environment/

SPECIFICATIONS

Maximum continuous current	4 A Note: Don't insert or remove relays while in the energized condition.			
Breakdown voltage	1,500 Vrms between terminals			
Insulation resistance	More than 100 $\text{M}\Omega$ between terminals at 500 V DC Mega			
Heat resistance	150 ±3°C (302 ±5.4°F) for 1 hour.			

Inserting and removing method

Inserting method: Insert the relay as shown in Fig. 1 unit the rib of the relay snaps into the clip of the socket.

Removing method:

(1) Remove the relay straight from the socket holding the shaded portion of the relay as shown in Fig. 2.

(2) When sockets are mounted in close proximity, use a slotted screw driver as shown in Fig. 3.

